Product Document

Published by ams OSRAM Group





CMOSIS / AWAIBA

is now

Member of the ams Group

The technical content of this CMOSIS / AWAIBA document is still valid.

Contact information:

Headquarters:

ams AG Tobelbaderstrasse 30 8141 Premstaetten, Austria Tel: +43 (0) 3136 500 0 e-Mail: ams_sales@ams.com

Please visit our website at www.ams.com





CMV8000

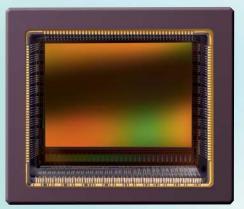
8MP high speed global shutter image sensor

SENSOR DESCRIPTION

The CMV8000 is a global shutter CMOS image sensor with 3360 by 2496 pixels in a 4/3" optical format. The image array consists of 5.5 um by 5.5 um pipelined global shutter pixels, which allow exposure during read out while performing CDS operation reducing fixed pattern and dark noise significantly. The CMV8000 has 16 digital LVDS outputs (serial) each running at 600 Mbps, which results in 104 fps frame rate at full resolution in 10-bit mode. Higher frame rates can be achieved in rowwindow-ing mode or row-subsampling mode. The image sensor also integrates a programmable gain amplifier and offset regulation. All operation modes are all programmable using a SPI interface. A programmable onboard sequencer generates all internal exposure and read out timings. External triggering and exposure programming is also possible. Extended optical dynamic range can be achieved by multiple integrated high dynamic range modes. A 12-bit per pixel mode is available at reduced frame rates.

APPLICATION FIELDS

- Machine vision
- Motion control
- Traffic monitoring
- High speed inspection
- Security



SENSOR FEATURES

- Pipelined global shutter with CDS
- 3360 (H) x 2496 (V) active pixels on a 5.5 μm pitch
- 2x 112 (left-right) optical black columns and 2x 16 (top-bottom) optical black rows
- Optical format of 4/3"
- 104 frames/s at full resolution in 10-bit mode (40 fps in 12-bit mode)
- ROI windowing capability (up to 8 separate ROIs - row based only)
- X-Y mirroring function
- 16 LVDS-outputs @ 600 Mbps multiplexable to 8, 4 and 2 at reduced frame rate
- Multiple High Dynamic Range (HDR) modes up to 90 dB
- On chip temperature sensor
- On chip timing generation
- SPI-control
- 3.3V and 1.8V signaling
- Monochrome and Bayer (RGB) configuration
- Ceramic 107-pins µPGA package (30.5 mm x 26.5 mm)
- 2 sided AR-coated cover glass lid

Please address all product inquiries and ordering information to:

CMOSIS · Coveliersstraat 15 · B-2600 Antwerpen · Phone: +32 3 260 17 33 · Fax: +32 3 260 17 79 · info@cmosis.com

Please visit our website for contact information on local distribution partners.





CMV8000

8MP high speed global shutter image sensor

SENSOR SPECIFICATIONS

Specification

Value

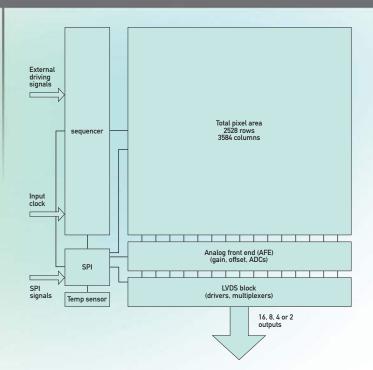
Part status Resolution Pixel size **Optical Format** Shutter Type

Frame Rate

Output Interface Sensitivity **Conversion** gain Full well charge Dark noise Dynamic range SNR max Parasitic light sensitivity Extended dynamic range Yes, up to 90 dB Dark current Fixed pattern noise Chroma Supply voltage Power Operating temperature range **RoHS** compliance Package Glass

Pre-Production 8MP - 3360 (H) x 2496 (V) 5.5 x 5.5 µm² 4/3" Pipelined global shutter with true CDS 104 fps (10 bit) 40 fps (12 bit) 16 LVDS outputs @ 600 Mbps 5.56 V/lux.s 0.077 LSB/e-11700 e-8.6 e- (RMS) 61 dB 41.3 dB 1/20000 41.2 e-/s (25°C) < 1 LSB (<0.1 % of full swing) Mono and RGB 1.8 V / 3.3 V 900 mW -30°C to +70°C

Yes 107 pins µPGA double sided AR coated



ORDERING INFORMATION

CMV8000

Description

CMV8000ES-1E5M1PA Monochrome version CMV8000ES-1E5M1PN Monochrome version with removeable glass lid CMV8000ES-1E5C1PA **RGB Bayer Color version**